

Product Summary

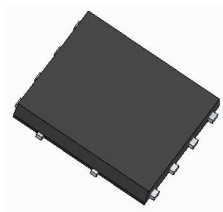
BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C (Note 9)
60V	10mΩ @ V _{GS} = 10V	89.5A
	12mΩ @ V _{GS} = 4.5V	81.7A

Description and Applications

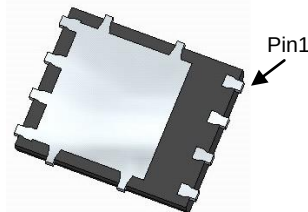
This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- High Frequency Switching
- Synchronous Rectification
- DC-DC Converters

PowerDI5060-8



Top View



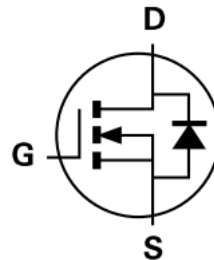
Bottom View

Features

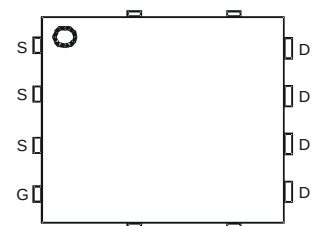
- Rated to +175°C – Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching – Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} – Minimizes Power Losses
- Low Q_G – Minimizes Switching Losses
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: PowerDI® 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.097 grams (Approximate)



Internal Schematic



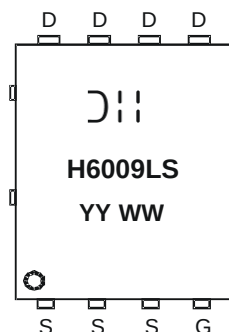
Top View
Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH6009LPS-13	PowerDI5060-8	2,500/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



DIII = Manufacturer's Marking
 H6009LS = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 16 = 2016)
 WW = Week (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±16	V
Continuous Drain Current (Note 5)	T _A = +25°C	I _D	11.76	A
	T _A = +100°C		8.3	
Continuous Drain Current (Note 6)	T _C = +25°C (Note 9)	I _D	89.5	A
	T _C = +100°C		63.3	
Maximum Continuous Body Diode Forward Current (Note 6)		I _S	100	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		I _{DM}	160	A
Avalanche Current, L=0.1mH		I _{AS}	20.3	A
Avalanche Energy, L=0.1mH		E _{AS}	20.6	mJ

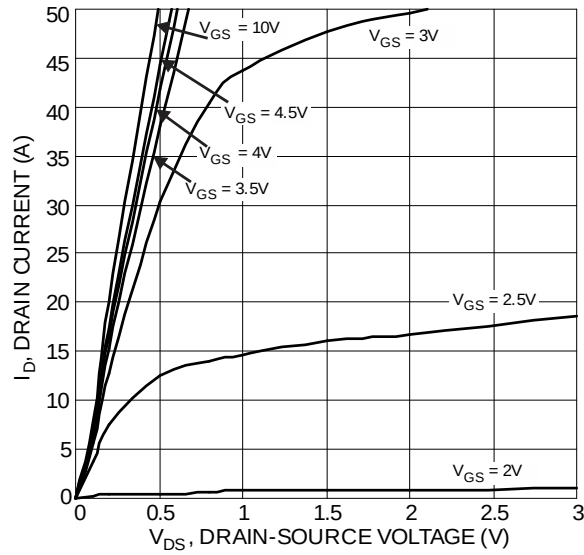
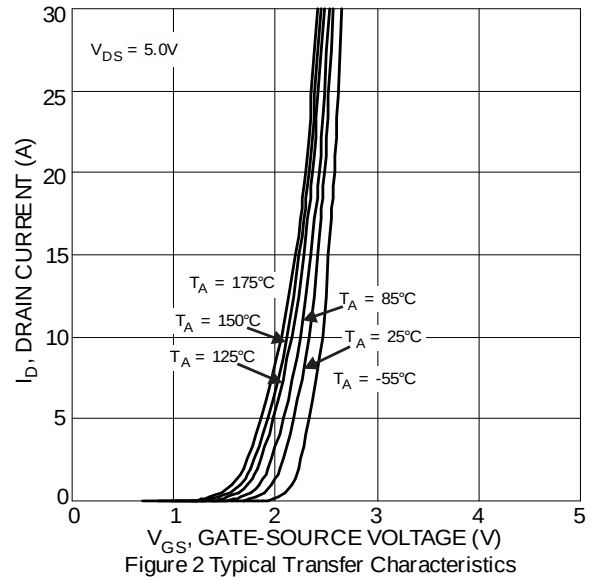
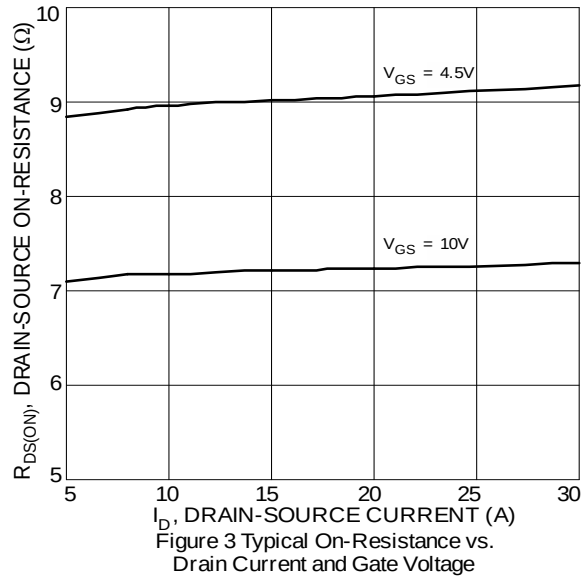
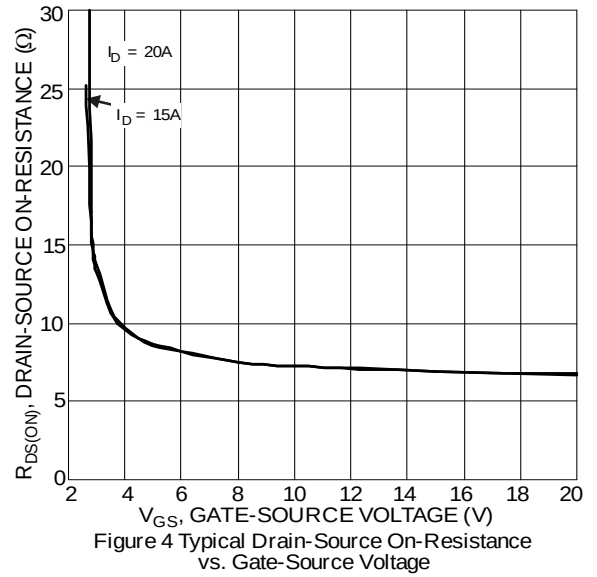
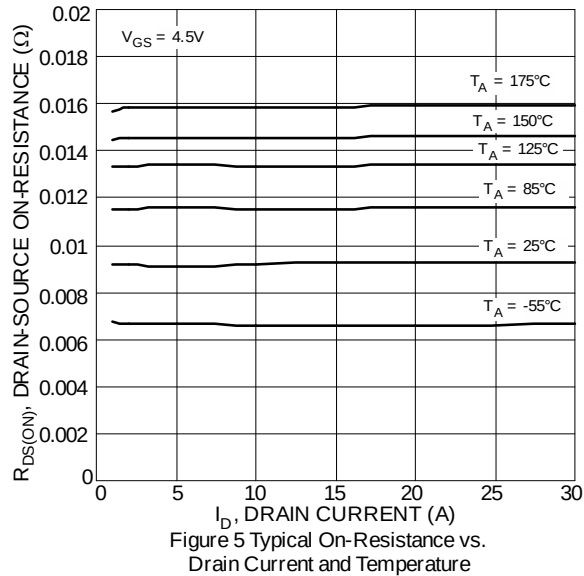
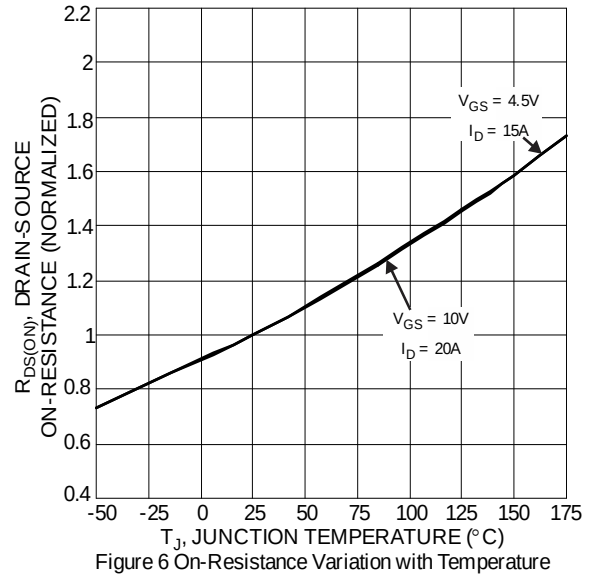
Thermal Characteristics

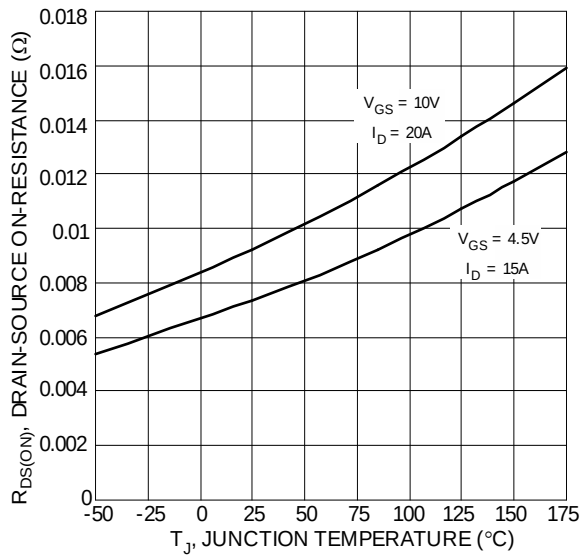
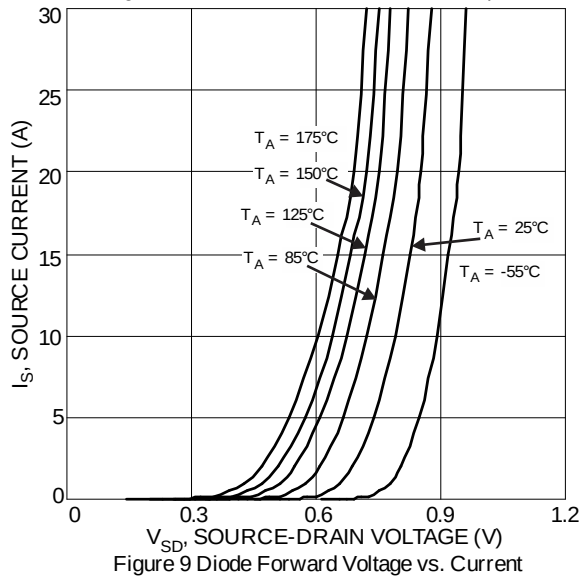
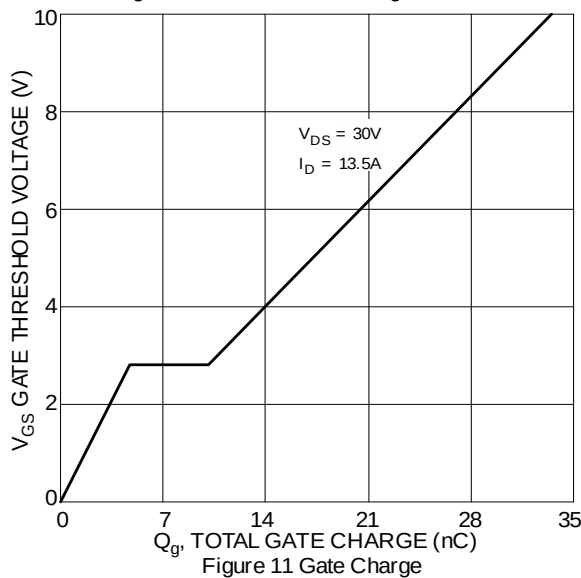
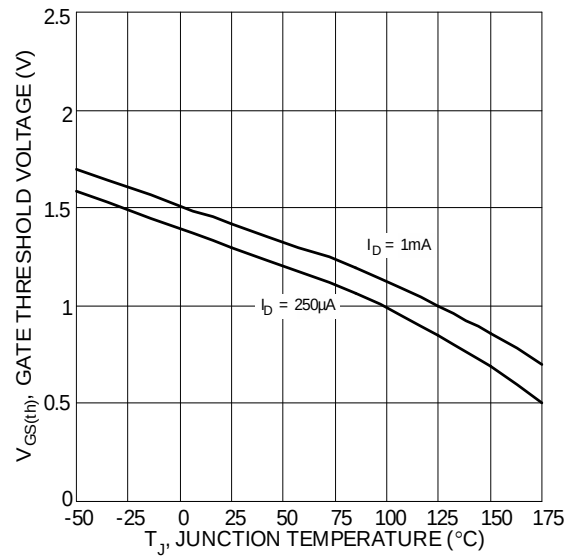
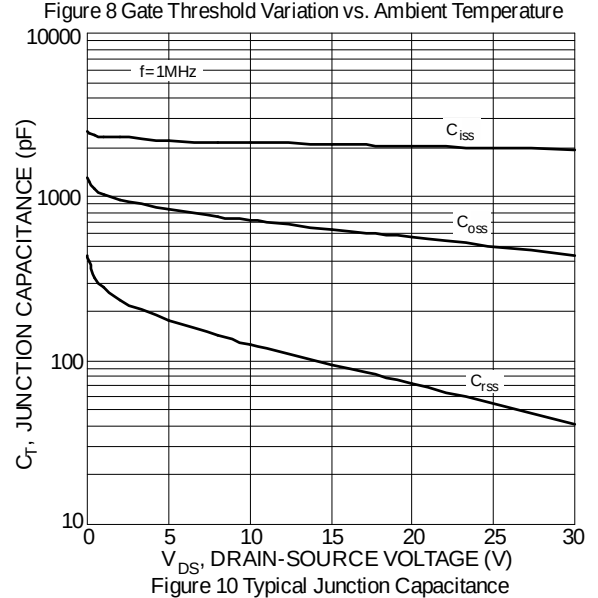
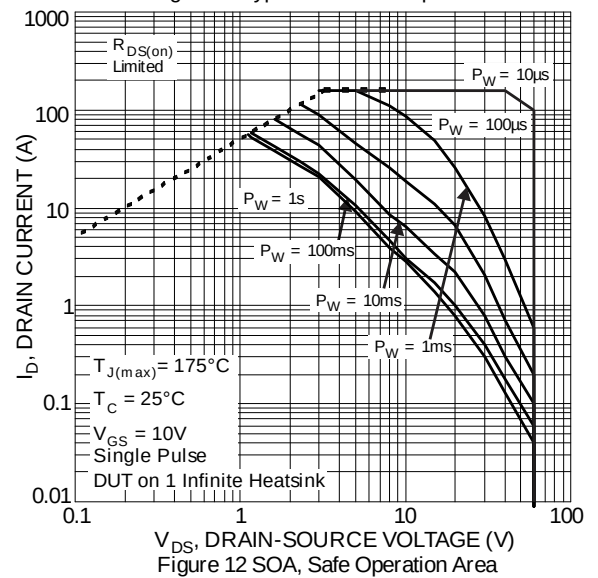
Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	P _D	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{θJA}	53	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	P _D	136	W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	1.1	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

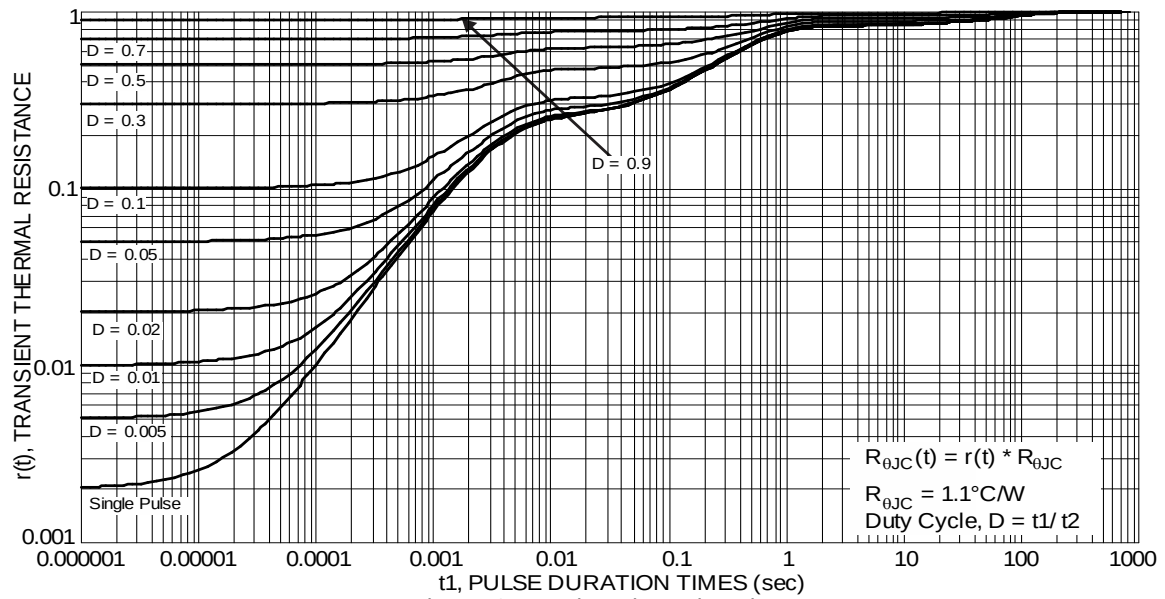
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	V _{GS} = 0V, I _D = 1mA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1	μA	V _{DS} = 48V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±16V, V _{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.7	—	2	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	7.2	10	mΩ	V _{GS} = 10V, I _D = 20A
		—	8.9	12		V _{GS} = 4.5V, I _D = 15A
Diode Forward Voltage	V _{SD}	—	0.9	—	V	V _{GS} = 0V, I _S = 20A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{ISS}	—	1,925	—	pF	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz
Output Capacitance	C _{OSS}	—	438	—		
Reverse Transfer Capacitance	C _{RSS}	—	41	—		
Gate resistance	R _G	—	1.7	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = 10V)	Q _G	—	33.5	—	nC	V _{DS} = 30V, I _D = 13.5A
Total Gate Charge (V _{GS} = 4.5V)	Q _G	—	15.6	—		
Gate-Source Charge	Q _{GS}	—	4.7	—		
Gate-Drain Charge	Q _{GD}	—	5.3	—		
Turn-On Delay Time	t _{D(ON)}	—	4.5	—	ns	V _{DD} = 30V, V _{GS} = 10V, R _G = 6Ω, I _D = 13.5A
Turn-On Rise Time	t _R	—	8.6	—		
Turn-Off Delay Time	t _{D(OFF)}	—	35.9	—		
Turn-Off Fall Time	t _F	—	15.7	—		
Body Diode Reverse Recovery Time	t _{RR}	—	18.2	—	ns	I _F = 13.5A, di/dt = 400A/μs
Body Diode Reverse Recovery Charge	Q _{RR}	—	33.1	—	nC	

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 - Thermal resistance from junction to soldering point (on the exposed drain pad).
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.
 - Package limited.



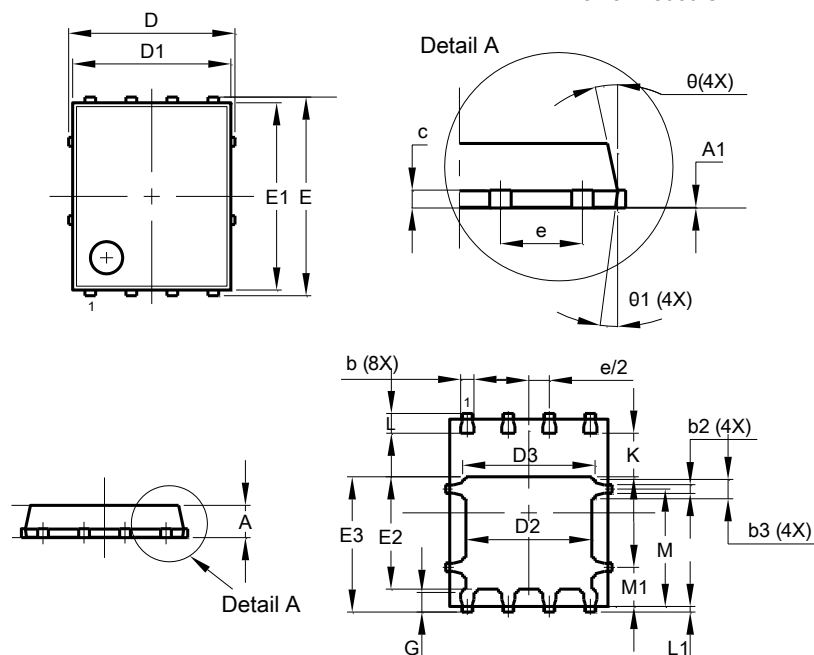




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI5060-8

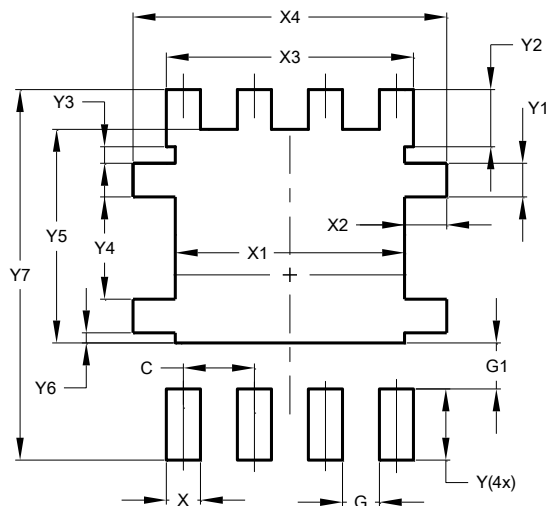


PowerDI5060-8			
Dim	Min	Max	Typ
A	0.90	1.10	1.00
A1	0.00	0.05	—
b	0.33	0.51	0.41
b2	0.200	0.350	0.273
b3	0.40	0.80	0.60
c	0.230	0.330	0.277
D	5.15 BSC		
D1	4.70	5.10	4.90
D2	3.70	4.10	3.90
D3	3.90	4.30	4.10
E	6.15 BSC		
E1	5.60	6.00	5.80
E2	3.28	3.68	3.48
E3	3.99	4.39	4.19
e	1.27 BSC		
G	0.51	0.71	0.61
K	0.51	—	—
L	0.51	0.71	0.61
L1	0.100	0.200	0.175
M	3.235	4.035	3.635
M1	1.00	1.40	1.21
θ	10°	12°	11°
θ1	6°	8°	7°
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
C	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

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